

The Future of Analog IC Technology

DESCRIPTION

The MP1472 is a monolithic synchronous buck regulator. The device integrates a $175m\Omega$ high-side MOSFET and a $115m\Omega$ low-side MOSFET that provide 2A of continuous load current over a wide input voltage of 4.75V to 18V. Current mode control provides fast transient response and cycle-by-cycle current limit.

An adjustable soft-start prevents inrush current at turn-on, and in shutdown mode the supply current drops to 1µA.

This device, available in an 8-pin TSOT23-8 package, provides a very compact solution with minimal external components.

EVALUATION BOARD REFERENCE

Board Number	Dimensions
EV1472GJ-00A	2.5"X x 2.5"Y x 0.5"Z

FEATURES

- 2A Output Current
- Wide 4.75V to 18V Operating Input Range
- Integrated Power MOSFET Switches
- Output Adjustable from 0.923V to 15V
- Up to 95% Efficiency
- Programmable Soft-Start
- Stable with Low ESR Ceramic Output Capacitors
- Fixed 340kHz Frequency
- Cycle-by-Cycle Over Current Protection
- Input Under Voltage Lockout
- 8–Pin TSOT23-8

APPLICATIONS

- Distributed Power Systems
- Networking Systems
- FPGA, DSP, ASIC Power Supplies
- Green Electronics/ Appliances
- Notebook Computers

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TYPICAL APPLICATION



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ORDERING INFORMATION

Part Number	Package	Top Marking
MP1472GJ*	TSOT23-8	ACW

*For Tape & Reel, add suffix –Z (e.g. MP1472GJ–Z);

PACKAGE REFERENCE



ABSOLUTE MAXIMUM RATINGS (1)

Supply Voltage V _{IN}	0.3V to +20V
Switch Node Voltage V _{SW}	21V
Boost Voltage V _{BS} V _{SW} –	0.3V to V _{SW} + 6V
All Other Pins	0.3V to +6V
Junction Temperature	150°C
Continuous Power Dissipation	(T _A = +25°C)
	1.25\//

Lead Temperature	260°C
Storage Temperature	65°C to +150°C

Recommended Operating Conditions ⁽³⁾

Input Voltage V _{IN}	
Output Voltage Vout	0.923V to 15V
Maximum Junction Temp. (1	「」)+125°C

Thermal Resistance $^{(4)}$ θ_{JA} θ_{JC}

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TSOT23-8..... 100..... 55... °C/W
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Notes:

- 2) The maximum allowable power dissipation is a function of the maximum junction temperature $T_J(MAX)$, the junction-toambient thermal resistance θ_{JA} , and the ambient temperature T_A . The maximum allowable continuous power dissipation at any ambient temperature is calculated by $P_D(MAX)=(T_J(MAX)-T_A)/\theta_{JA}$. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on JESD51-7 4-layer PCB.

¹⁾ Exceeding these ratings may damage the device.